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# JVSTB

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## Nanotechnology and Microelectronics: Materials, Processing, Measurement, and Phenomena

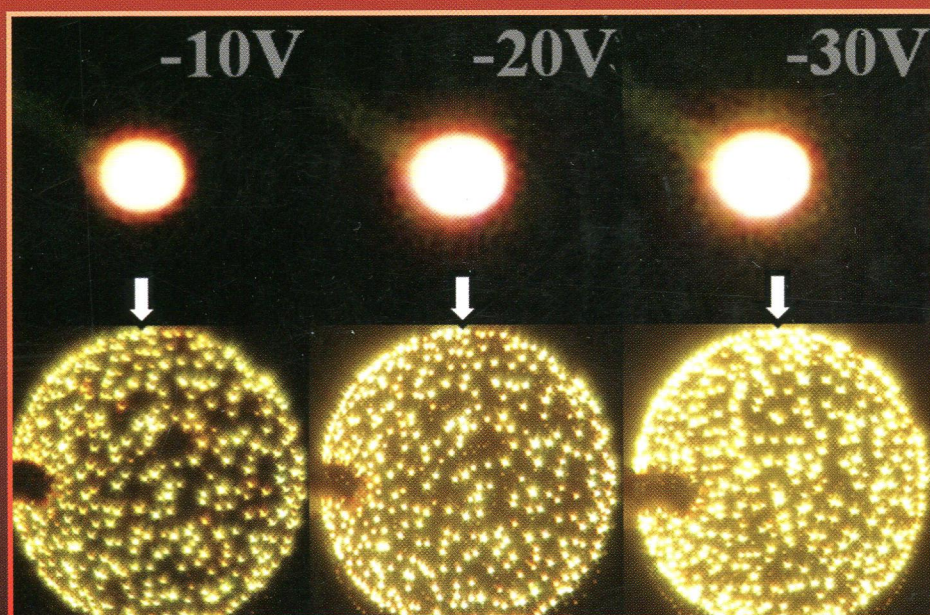
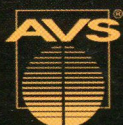


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## Nanotechnology and Microelectronics:

## Materials, Processing, Measurement, and Phenomena

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**On The Cover:** Chi-Chou Lin and Yue Kuo, *JVST B*, 32(1), p. 011208-3 (2014). Cover shows the low- and high-magnification photos of a new type of WO<sub>3</sub> LED driven at different voltages.